

P-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- Surface-mounted package
- Advanced trench cell design

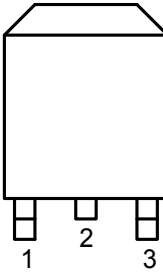
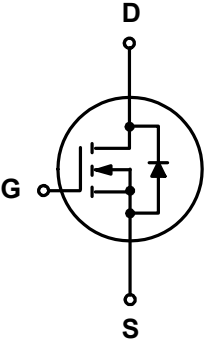
1.2 Applications

- Portable appliances
- Battery management
- High speed switch
- Low power DC to DC Converter

1.3 Quick reference

- $BV \leq -60\text{ V}$
- $R_{DS(ON)} \leq 140\text{ m}\Omega @ V_{GS} = -10\text{ V}$
- $P_{tot} \leq 35\text{ W}$
- $R_{DS(ON)} \leq 180\text{ m}\Omega @ V_{GS} = -4.5\text{ V}$
- $I_D \leq -10\text{ A}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View TO252	
2	Drain(D)		
3	Source(S)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_A = 25\text{ }^\circ\text{C}$	- 60	-	V
V_{GS}	Gate-Source Voltage	$T_A = 25\text{ }^\circ\text{C}$	-	± 20	V
I_D^*	Drain Current	$T_A = 25\text{ }^\circ\text{C}, V_{GS} = -10\text{ V}$	-	- 10	A
		$T_A = 100\text{ }^\circ\text{C}, V_{GS} = -10\text{ V}$	-	- 8	A
$I_{DM}^{*,**}$	Pulsed Drain Current	$T_A = 25\text{ }^\circ\text{C}, V_{GS} = -10\text{ V}$	-	- 25	A
P_{tot}	Total Power Dissipation	$T_A = 25\text{ }^\circ\text{C}$	-	0.83	W
T_{stg}	Storage Temperature		- 55	150	$^\circ\text{C}$
T_J	Junction Temperature		- 55	150	$^\circ\text{C}$
I_S	Diode Forward Current	$T_A = 25\text{ }^\circ\text{C}$	-	- 10	A
$R_{\theta JA}^*$	Thermal Resistance- Junction to Ambient		-	150	$^\circ\text{C} / \text{W}$

Notes :

* Surface Mounted on 1 in² pad area, $t \leq 10\text{ sec}$

** Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

4. Marking Information

Product Name	Marking
KJ10P06K	<div style="display: inline-block; border: 1px solid black; padding: 2px;"> KJ10P06K YWWXXX </div> YWWXXX: Date Code

5. Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
KJ10P06K	T0252			2500	

Note: KUAJIEXIN defines " Green " as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

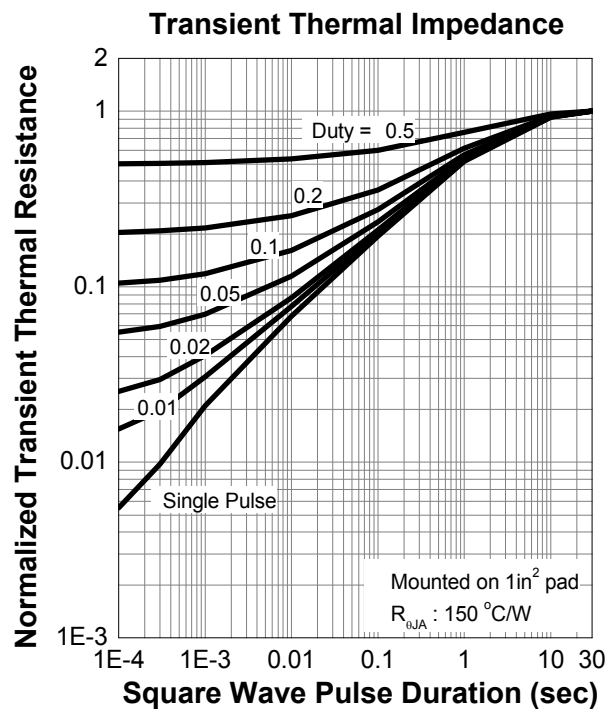
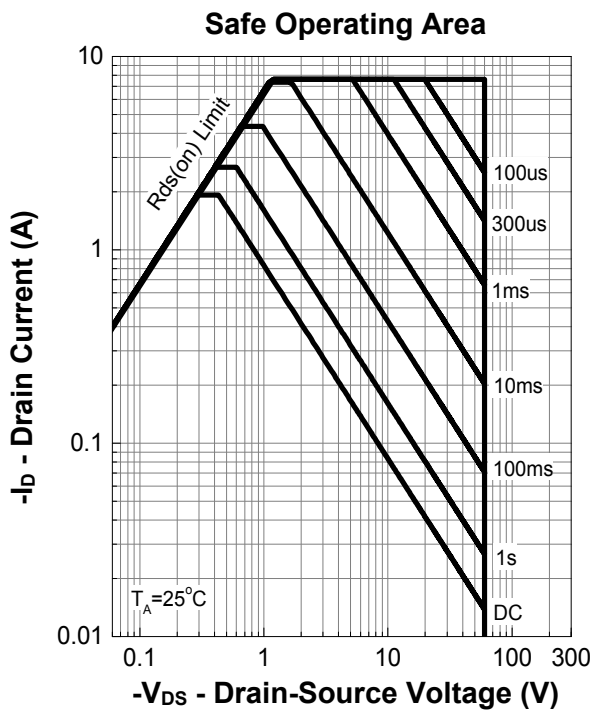
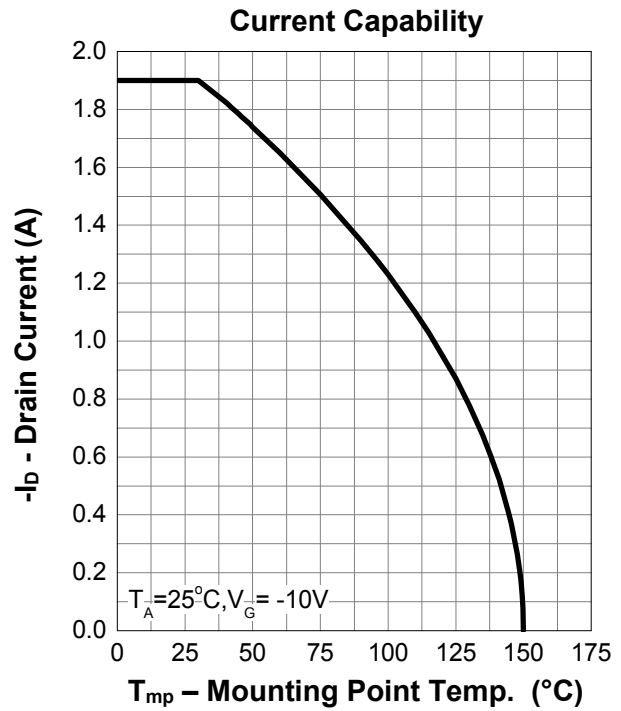
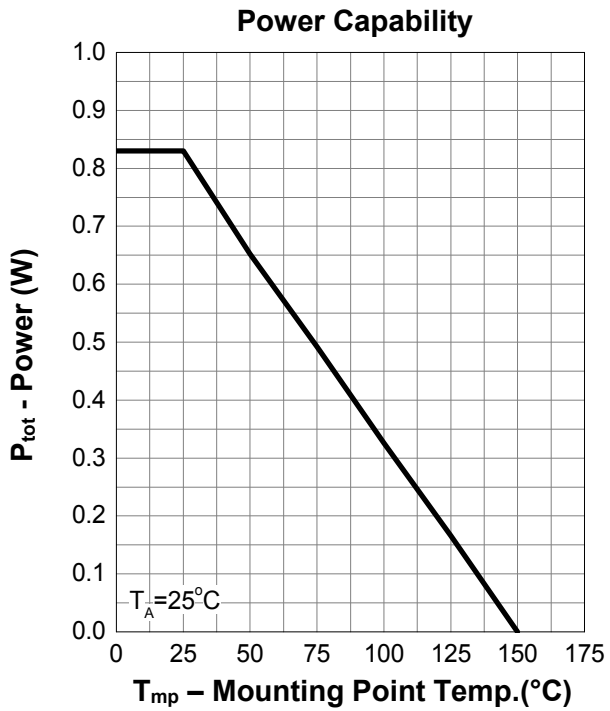
6. Electrical Characteristics ($T_A = 25\text{ }^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = -250\text{ }\mu\text{A}$	-60	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = -250\text{ }\mu\text{A}$	-1	-2	-3	V
I_{DSS}	Drain Leakage Current	$V_{DS} = -48\text{ V}, V_{GS} = 0\text{ V}$	-	-	-1	μA
		$T_J = 85\text{ }^\circ\text{C}$	-	-	-30	μA
I_{GSS}	Gate Leakage Current	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	-	-	± 100	nA
$R_{DS(ON)}^a$	On-State Resistance	$V_{GS} = -10\text{ V}, I_{DS} = -5\text{ A}$	-	125	140	m Ω
		$V_{GS} = -4.5\text{ V}, I_{DS} = -3\text{ A}$	-	165	180	
Diode Characteristics						
V_{SD}^a	Diode Forward Voltage	$I_{SD} = -1\text{ A}, V_{GS} = 0\text{ V}$	-	-0.8	-1.4	V
Dynamic Characteristics^b						
C_{iss}	Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = -15\text{ V}$ Frequency = 1 MHz	-	580	-	pF
C_{oss}	Output Capacitance		-	52	-	
C_{rss}	Reverse Transfer Capacitance		-	35	-	
$t_d(on)$	Turn-on Delay Time	$V_{DS} = -15\text{ V}, V_{GEN} = -10\text{ V},$ $R_G = 3.3\text{ }\Omega, R_L = 15\text{ }\Omega,$ $I_{DS} = -1\text{ A}$	-	17.4	-	ns
t_r	Turn-on Rise Time		-	5.4	-	
$t_d(off)$	Turn-off Delay Time		-	37.2	-	
t_f	Turn-off Fall Time		-	2.4	-	
Gate Charge Characteristics^b						
Q_g	Total Gate Charge	$V_{GS} = -10\text{ V}, V_{DS} = -20\text{ V},$ $I_{DS} = -1.5\text{ A}$	-	9.5	-	nC
Q_{gs}	Gate-Source Charge		-	1.52	-	
Q_{gd}	Gate-Drain Charge		-	1.76	-	

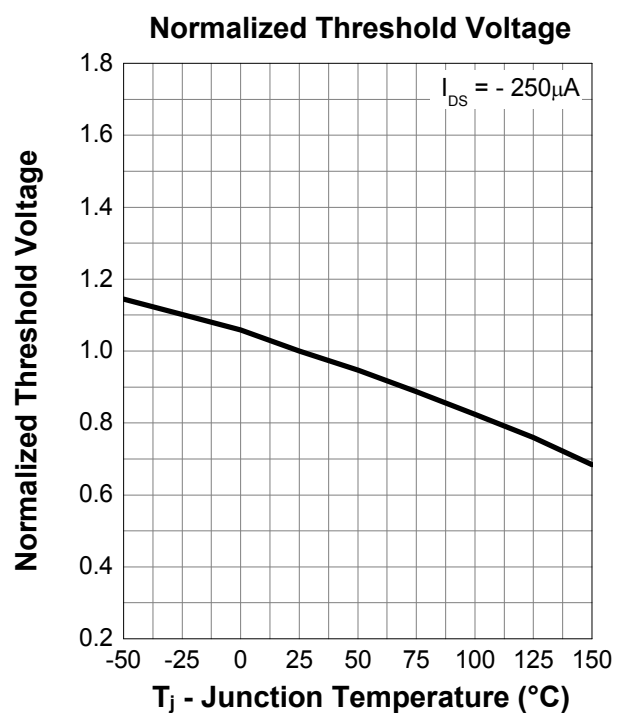
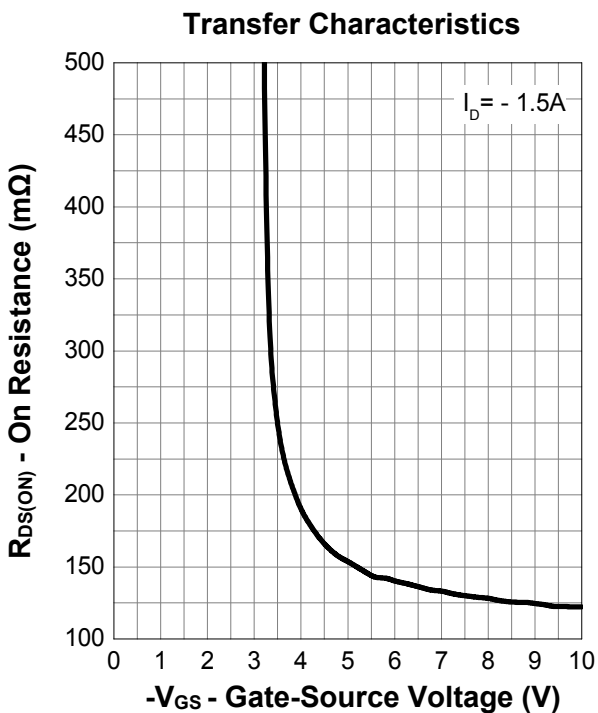
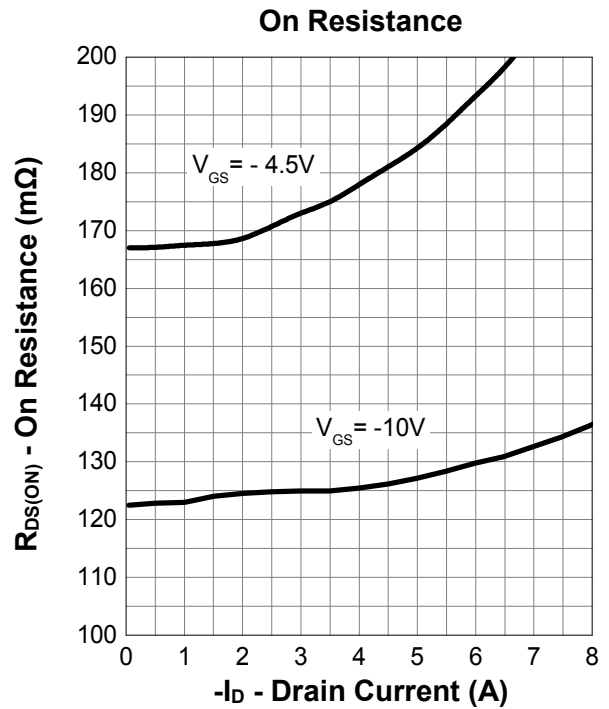
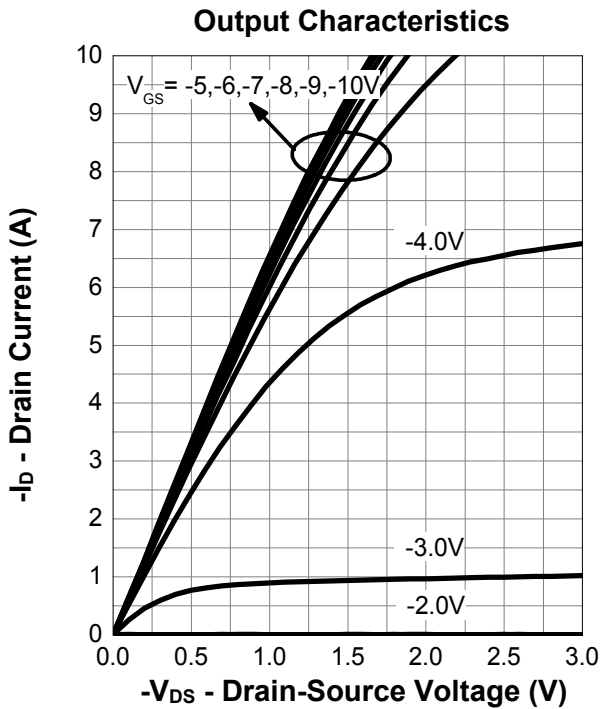
Notes : a : Pulse test ; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

b : Guaranteed by design, not subject to production testing

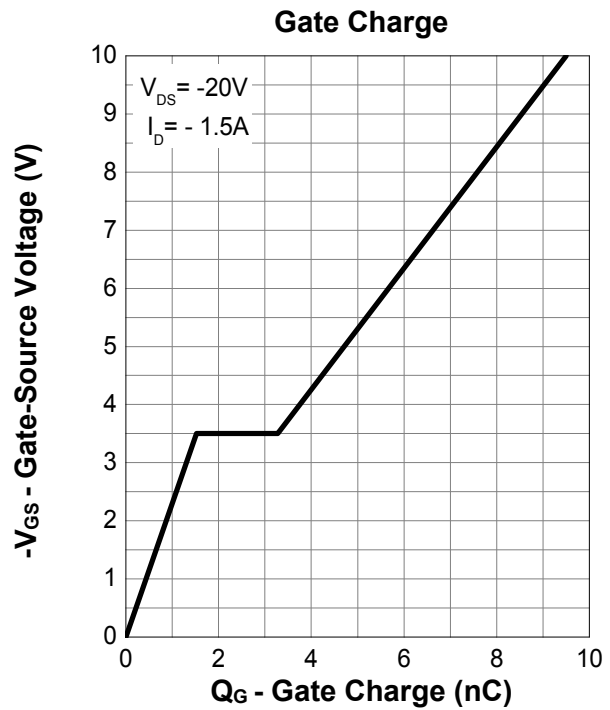
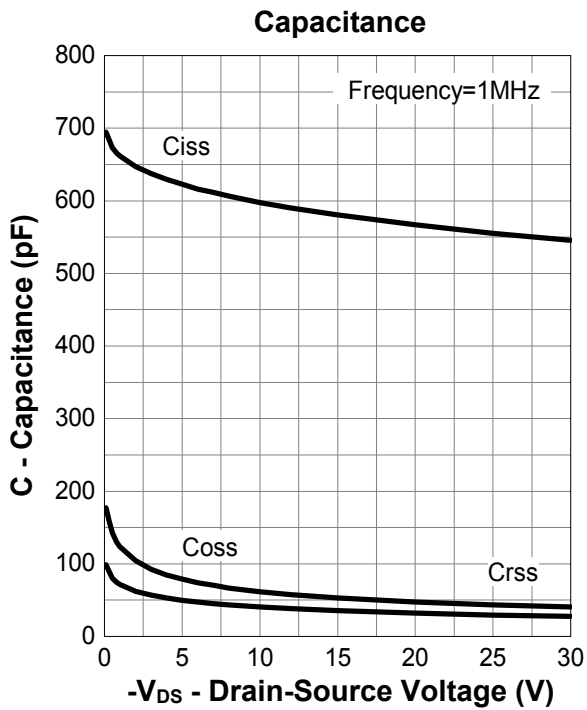
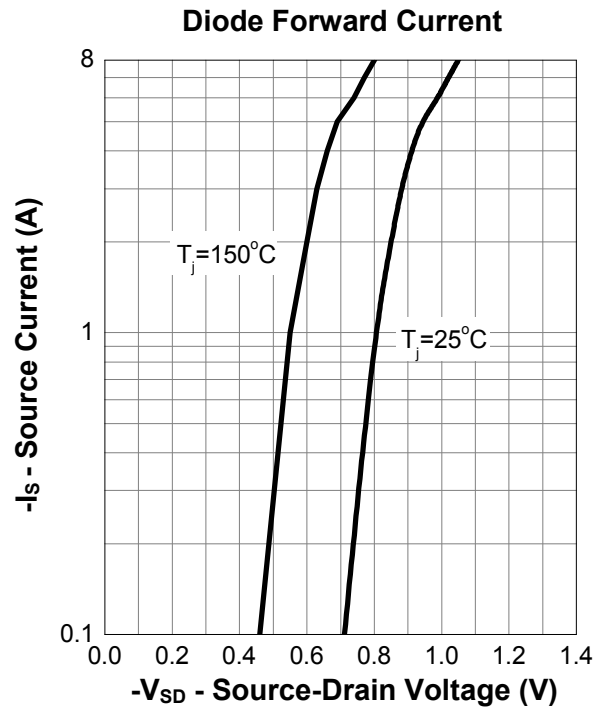
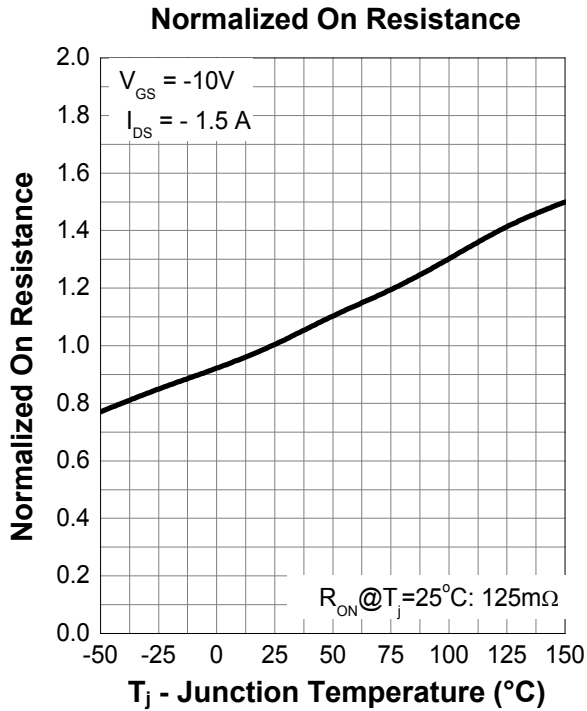
7. Typical Characteristics



7. Typical Characteristics (cont.)

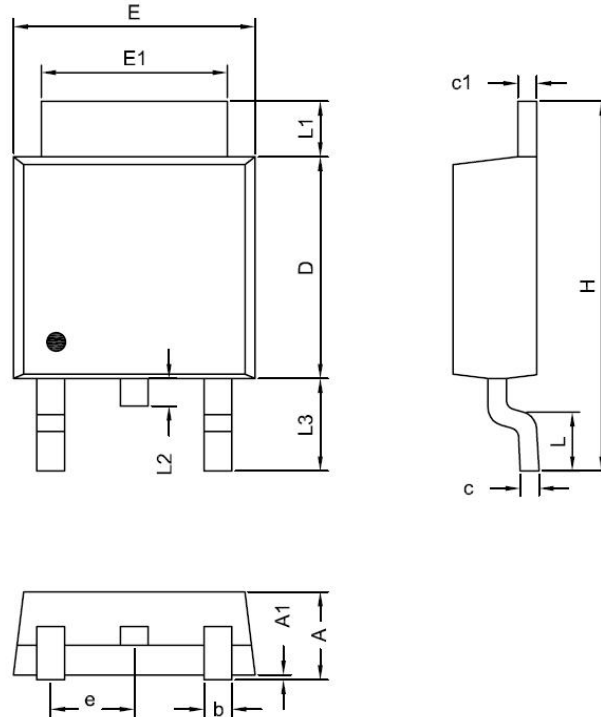


7. Typical Characteristics (cont.)



8.Package Dimensions

T0252-3L



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	2.19	2.38
A1	0.02	0.13
D	5.30	6.40
E	6.35	6.80
E1	5.20	5.50
c	0.40	0.60
c1	0.40	0.60
b	0.55	0.85
e	2.30 BCS	
L	1.00	1.80
L1	0.70	1.80
L2	0.70 BCS	
L3	2.40	2.80
H	9.20	10.40